

Docket No.: 2336-257

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	:	EXPEDITED PROCEDURE
Seung Wan CHAE <i>et al.</i>	:	Response under 37 CFR 1.116
	:	
U.S. Patent Application No. 10/811,808	:	Confirmation No. 2845
	:	Group Art Unit: 2814
Filed: March 30, 2004	:	Examiner: Wai Sing Louie

For: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE
AND METHOD FOR MANUFACTURING THE SAME

REQUEST FOR RECONSIDERATION

COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria VA 22313-1450

Sir:

This paper is submitted in reply to the Office Action mailed March 8, 2006, which was made Final.